

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The μ PA1815 is a switching device which can be driven directly by a 2.5-V power source.

The μ PA1815 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- Can be driven by a 2.5-V power source
- Low on-state resistance

 $\begin{array}{l} {\sf R}_{\sf DS(on)1} = 15 \mbox{ m}\Omega \mbox{ MAX.} ({\sf VGS} = -4.5 \mbox{ V}, \mbox{ ID} = -3.5 \mbox{ A}) \\ {\sf R}_{\sf DS(on)2} = 16 \mbox{ m}\Omega \mbox{ MAX.} ({\sf VGS} = -4.0 \mbox{ V}, \mbox{ ID} = -3.5 \mbox{ A}) \\ {\sf R}_{\sf DS(on)3} = 19 \mbox{ m}\Omega \mbox{ MAX.} ({\sf VGS} = -3.3 \mbox{ V}, \mbox{ ID} = -3.5 \mbox{ A}) \\ {\sf R}_{\sf DS(on)4} = 23 \mbox{ m}\Omega \mbox{ MAX.} ({\sf VGS} = -2.5 \mbox{ V}, \mbox{ ID} = -3.5 \mbox{ A}) \\ \end{array}$

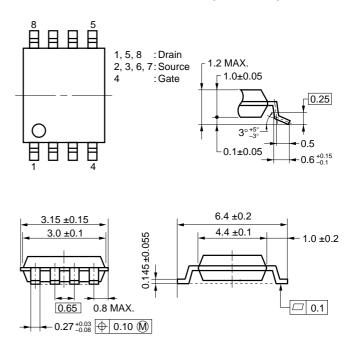
ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1815GR-9JG	Power TSSOP8

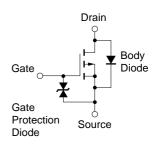
ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage	Vdss	-20	V
Gate to Source Voltage	Vgss	±12	V
Drain Current (DC)	D(DC)	±7	А
Drain Current (pulse) ^{Note1}	D(pulse)	±26	А
Total Power Dissipation Note2	Рт	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

PACKAGE DRAWING (Unit : mm)



EQUIVALENT CIRCUIT



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

- 2. Mounted on ceramic substrate of 5000 mm² x 1.1 mm
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

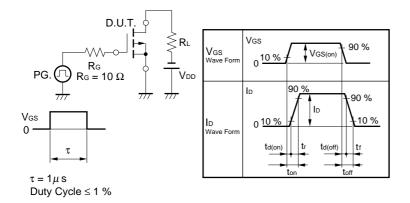
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★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

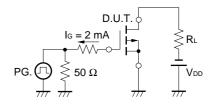
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	loss	$V_{DS} = -20 V$, $V_{GS} = 0 V$			-10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 12 V$, $V_{DS} = 0 V$			±10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 V, I_{D} = -1 mA$	-0.5	-0.9	-1.5	V
Forward Transfer Admittance	yfs	$V_{DS} = -10 V$, $I_{D} = -3.5 A$	9	19		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -4.5 V$, $I_{D} = -3.5 A$		12	15	mΩ
	RDS(on)2	$V_{GS} = -4.0 \text{ V}, \text{ ID} = -3.5 \text{ A}$		13	16	mΩ
	RDS(on)3	$V_{GS} = -3.3 V$, $I_D = -3.5 A$		14	19	mΩ
	RDS(on)4	$V_{GS} = -2.5 V, I_D = -3.5 A$		17	23	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		3000		pF
Output Capacitance	Coss	Vgs = 0 V		790		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		410		pF
Turn-on Delay Time	t d(on)	$V_{DD} = -10 V$		45		ns
Rise Time	tr	I⊳ = −3.5 A		200		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = -4.0 V$		140		ns
Fall Time	tr	Rg = 10 Ω		160		ns
Total Gate Charge	QG	VDD = -16 V		25		nC
Gate to Source Charge	QGS	ID = -7 A		5		nC
Gate to Drain Charge	Qgd	Vgs = -4.0 V		8.5		nC
Diode Forward Voltage	VF(S-D)	IF = 7 A, VGS = 0 V		0.78		V
Reverse Recovery Time	trr	IF = 7 A, VGS = 0 V		60		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		45		nC

TEST CIRCUIT 1 SWITCHING TIME



TEST CIRCUIT 2 GATE CHARGE



-10

-100

125°C 75°C 25°C –25°C

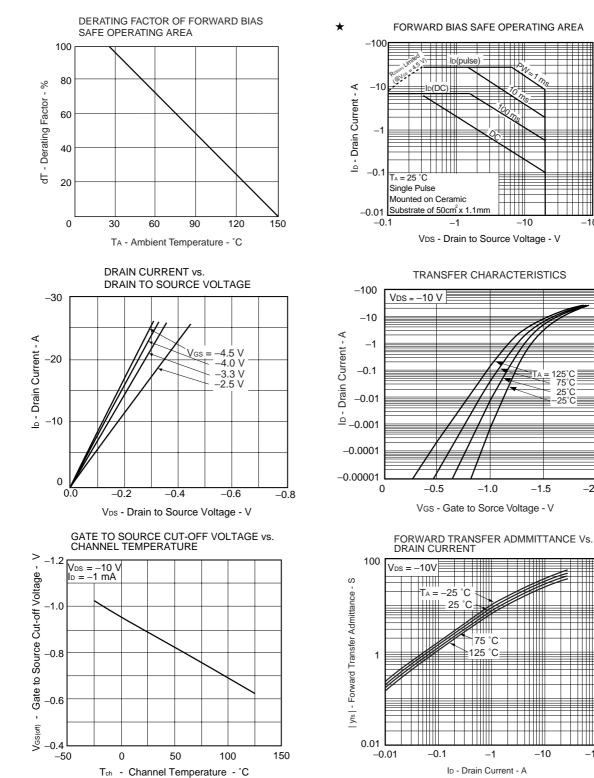
-2.0

-1.5

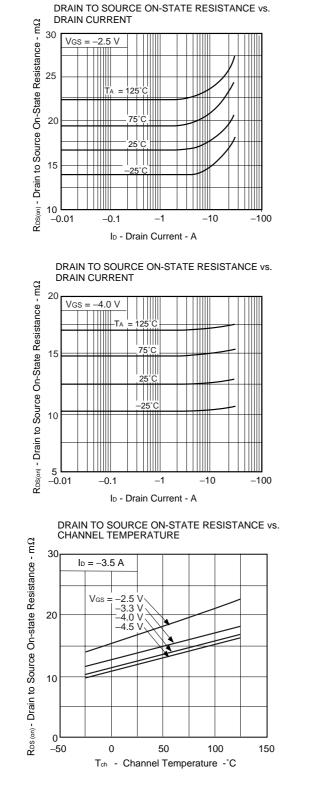
-10

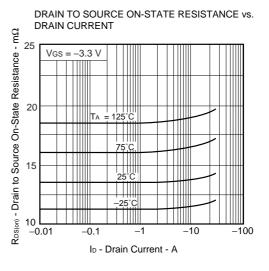
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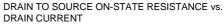
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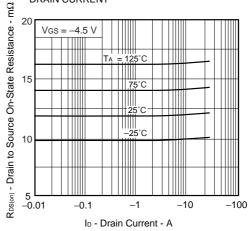


TYPICAL CHARACTERISTICS (TA = 25 °C)

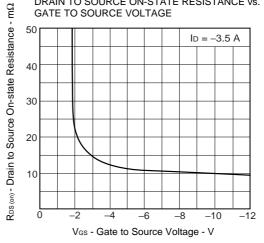




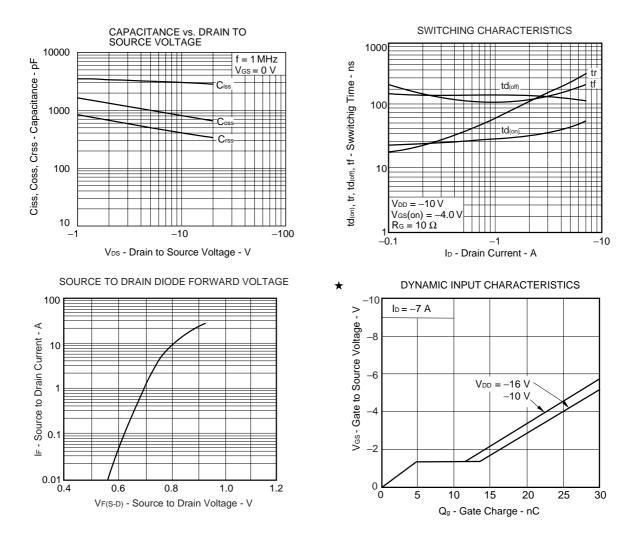




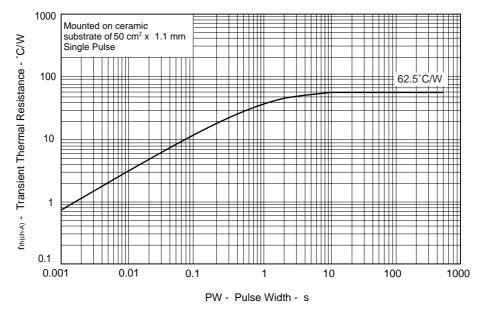




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TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



Data Sheet D13805EJ2V0DS00

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